SILICON CARBIDE (SiC) SCHOTTKY DIODE ▲ B2D30065HC1



BASiC

B2D30065HC1

Common cathode circuit configuration

Temperature independent switching

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TO-247-3L package ▲ Epoxy meets UL94-V0

Ultra-low forward voltage and high surge current

650V A 2x15A A SIC SCHOTTKY DIODE

Easy paralleling due to positive V_F temperature coefficient

SILICON CARBIDE SIC SCHOTTKY DIODE ▲ THT type



RoHS



SPECIFICATION

Item (T _c = 25°C, unless otherwise noted)	Characteristics	
Operating Temperature Range	TJ	-55°C to +175°C
Storage Temperature Range	Ts	-55°C to +175°C
Repetitive Peak Reverse Voltage	V _{RRM}	650V
Continuous Forward Current at $T_c = 155^{\circ}C^{\text{Note 1}}$	I _F	15A
Continuous Forward Current at T _c = 155°C Note 2	I _F	30A
Total Capacitive Charge (T _J = 25°C) Note 2	Qc	90nC
Diode Forward Voltage (T _J = 175°C, I_F = 15A) ^{Note 1}	V _F	1.32V
Power Dissipation Note 1	Ρτοτ	217W

Notes

1: Per leg

2: Per device

APPLICATIONS

EV Charging	Industrial Inverters	Motors & Drives	Power Factor Correction	Renewable Energy	SMPS	UPS
€Ո⊧			PFC	*		

PIN DESCRIPTION

Circuit Diagram	Outline - Front View	Pin No.	Description
Backside		1 2 3	Anode Diode 1 Common Cathode (Backside) Anode Diode 2

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ABSOLUT MAXIMUM RATINGS A T_c = 25°C, unless otherwise noted

Item	Condition	Symbol		Unit
Repetitive Peak Reverse Voltage		V _{RRM}	650	V
Non-Repetitive Peak Reverse Voltage		V _{RSM}	650	V
Continuous Forward Current	T _c = 25°C	IF	53 Note 1 / 106 Note 2	А
Continuous Forward Current	T _C = 125°C	IF	28 Note 1 / 56 Note 2	А
Continuous Forward Current	T _C = 155°C	IF	15 Note 1 / 30 Note 2	А
Non-Repetitive Forward Surge Current	T_{C} = 25°C, t_{p} = 10ms, Half Sine Wave	I _{FSM}	103 Note 1	А
I ² t Value	T _c = 25°C, t _p = 10ms	∫i²dt	53 Note 1	A ² s
Power Dissipation	T _C = 25°C	P _{TOT}	217 Note 1	W
Power Dissipation	T _C = 110°C	P _{TOT}	94 Note 1	W
Operating Junction Temperature		ТJ	-55 to +175	°C
Storage Temperature Range		T _{STG}	-55 to +175	°C
TO-247 Mounting Torque	M3 Screw		0.7	Nm

Notes

1: Per leg

2: Per device

ELECTRICAL CHARACTERISTICS ▲ PER LEG

ltem	Condition	Symbol	Min.	Тур.	Max.	Unit
Static Characteristics						
DC Blocking Voltage	T _J = 25°C	V_{DC}	650			V
Diode Forward Voltage	I _F = 15A, T _J = 25°C	V _F		1.32	1.60	V
Diode Forward Voltage	I _F = 15A, T _J = 175°C	VF		1.68	2.40	V
Reverse Current	$V_{R} = 650V, T_{J} = 25^{\circ}C$	I _R		1	110	μΑ
Reverse Current	V _R = 650V, T _J = 175°C	I _R		15	150	μA
Item	Condition	Symbol	Min.	Тур.	Max.	Unit
Dynamic Characteristics						
	$V_{R} = 400V, T_{J} = 25^{\circ}C$					
Total Capacitive Charge	$Q_C = \int_0^{V_R} C(V) dV$	Q _C		45		nC
Total Capacitance	$V_{R} = 1V, f = 1MHz, T_{J} = 25^{\circ}C$	С		705		рF
Total Capacitance	V _R = 300V, f = 1MHz, T _J = 25°C	С		78		pF
Total Capacitance	V _R = 600V, f = 1MHz, T _J = 25°C	С		74		pF
Capacitance Stored Energy	V _R = 400V, T _J = 25°C	Ec		11		μ

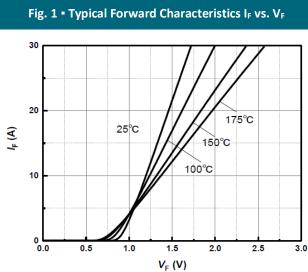
THERMAL RESISTANCE PERFORMANCE

Item	Symbol	Min.	Тур.	Max.	Unit
Thermal Resistance, Junction to Case, per Leg	$R_{\theta,JC}$		0.69		K/W
Thermal Resistance, Junction to Case, per Device	$R_{\theta,JC}$		0.35		K/W



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REFERENCE DATA A TYPICAL PERFORMANCE PER LEG



150°

175°(

0.1

Fig. 2 • Typical Reverse Current I_R as

function of Reverse Voltage V_R

1.5 2.0 2.5 3.0 V_F (V)

Fig. 3 • Diode Forward Current I_F as function of Case Temperature T_C (D = Duty Cycle)

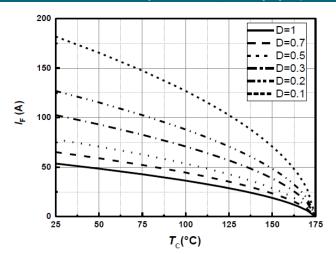


Fig. 4 • Typical Capacitance C as function of Reverse Voltage V_R , C =f(V_R), T_J = 25°C, f = 1MHz

400

*V*_R (V)

100°C

25°C

800

600

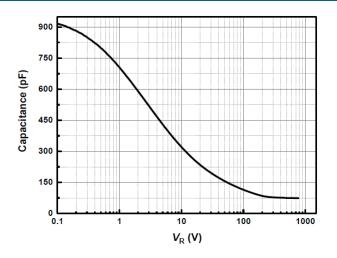


Fig. 5 • Typical Reverse Charge Q_C as function of Reverse Voltage V_R

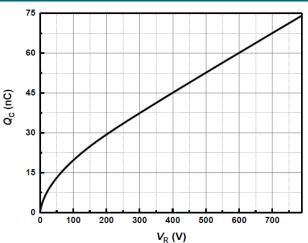
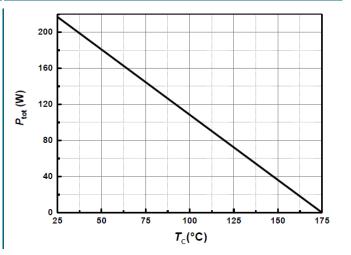


Fig. 6 • Power Dissipation P_{TOT} as function of Case Temperature T_C



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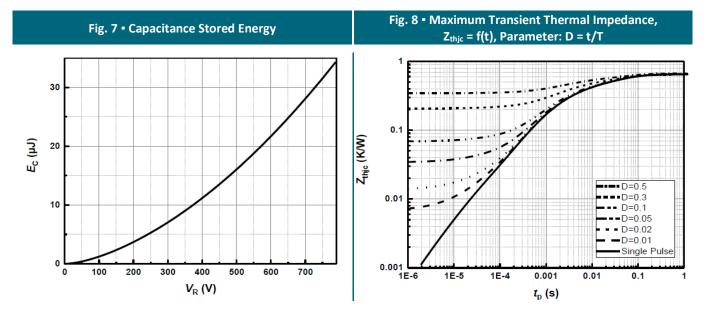
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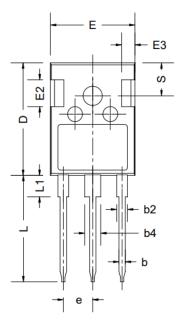
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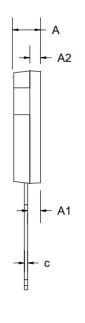
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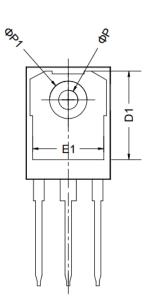




PACKAGE OUTLINE







Sym	Millimeters (Min.)	Millimeters (Typ.)	Millimeters (Max.)	Sym	Millimeters (Min.)	Millimeters (Typ.)	Millimeters (Max.)
А	4.80	5.00	5.20	E1	13.00	13.30	13.60
A1	2.21	2.41	2.59	E2	4.80	5.00	5.20
A2	1.85	2.00	2.15	E3	2.30	2.50	2.70
b	1.11	1.21	1.36	е		5.44 BSC	
b2	1.91	2.01	2.21	L	19.62	19.92	20.22
b4	2.91	3.01	3.21	L1	-	-	4.30
с	0.51	0.61	0.75	ØР	3.40	3.60	3.80
D	20.80	21.00	21.30	ØP1	-	-	7.30
D1	16.25	16.55	16.85	S		6.16 BSC	
E	15.50	15.80	16.10				

ORDERING INFORMATION

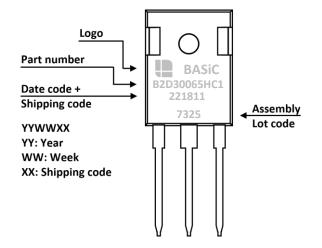
Part Number	Package	Packing	Tube Qty.	Inner Box Qty.	Outer Box Qty.
B2D30065HC1	TO-247-3L	Tube	30pcs	600pcs	3,000pcs

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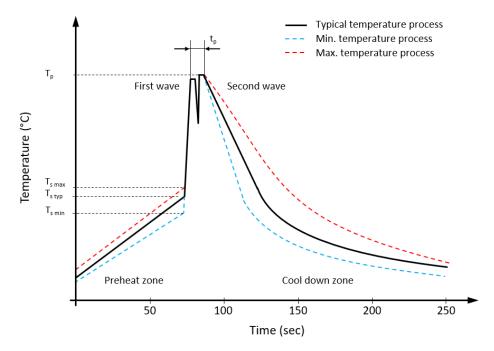


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PART MARKING



RECOMMENDED WAVE SOLDERING PROFILE A THT PACKAGE



Classification wave soldering profile **A** Refer to EN 61760-1: 2006

Profile Features		Value 🔺 Sn-Pb Assembly	Value 🔺 Pb-free Assembly
Preheat temperature min.	T_{smin}	100 °C	100 °C
Preheat temperature typical	T _{s typ}	120 °C	120 °C
Preheat temperature max.	$T_{s max}$	130 °C	130 °C
Preheat time t_s from $T_{s min}$ to $T_{s max}$	ts	70 seconds	70 seconds
Peak temperature	Tp	235 °C to 260 °C	245 °C to 260 °C
Time of actual peak temperature	tp	Max. 10 seconds Max. 5 second each wave	Max. 10 seconds Max. 5 second each wave
Ramp-down date min.		~ 2 °C/second	~ 2 °C/second
Ramp-down rate typical		~ 3.5 °C/second	~ 3.5 °C/second
Ramp-down rate max.		~ 5 °C/second	~ 5 °C/second

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REVISION TABLE

Revision	Date	Status	Notes
001	30/09/2022	Initial release	Initial publication

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